NCE N-Channel Super Trench Power MOSFET

Description

The NCEP01T18 uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

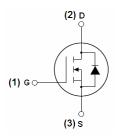
- $V_{DS} = 100V, I_D = 180A$ $R_{DS(ON)} < 3.0 m\Omega @ V_{GS} = 10V$
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



TO-220-3L top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP01T18	NCEP01T18	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_C=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	100	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	180	Α
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	128	Α
Pulsed Drain Current	I _{DM}	720	А
Maximum Power Dissipation	P _D	300	W
Derating factor		2	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	1800	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C



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NCEP01T18

Thermal Characteristic

Thermal Resistance, Junction-to-Case (Note 2)	Rejc	0.5	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	100		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)			•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.5	-	4.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =100A	- 1	2.8	3.0	mΩ
Forward Transconductance	g FS	V _{DS} =10V,I _D =50A	40	-	-	S
Dynamic Characteristics (Note4)		O				
Input Capacitance	C _{lss}	V -50V/V C0V	-	11500	-	PF
Output Capacitance	C _{oss}	V_{DS} =50 $V_{V_{GS}}$ =0 V_{S}	-	2480	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0ivir12	-	75	-	PF
Switching Characteristics (Note 4)	<u> </u>	6	•			
Turn-on Delay Time	t _{d(on)}	0.0	-	25	-	nS
Turn-on Rise Time	tr	V _{DD} =50V,I _D =100A	-	75	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =1.6 Ω	-	89	-	nS
Turn-Off Fall Time	t _f		-	29	-	nS
Total Gate Charge	Qg	V 50VI 400A	-	158		nC
Gate-Source Charge	Q _{gs}	V _{DS} =50V,I _D =100A,	-	52		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	29		nC
Drain-Source Diode Characteristics	<u> </u>					
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =180A	-		1.2	V
Diode Forward Current (Note 2)	I _S		-	-	180	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$	-	75		nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	185		nC

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25 $^{\circ}\text{C}$,VDD=50V,VG=10V,L=0.5mH,Rg=25 Ω

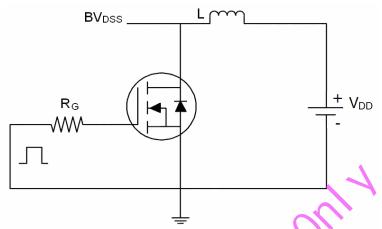
Pb Free Product



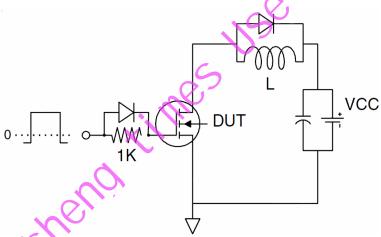
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Test Circuit

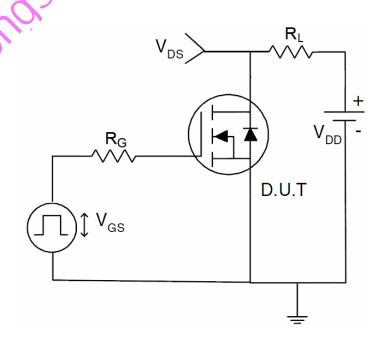
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics

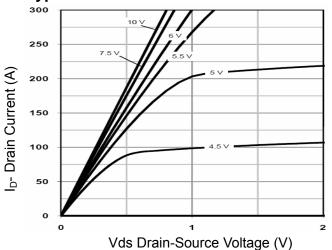


Figure 1 Output Characteristics

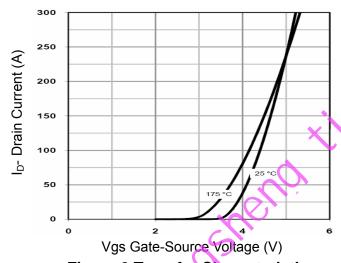


Figure 2 Transfer Characteristics

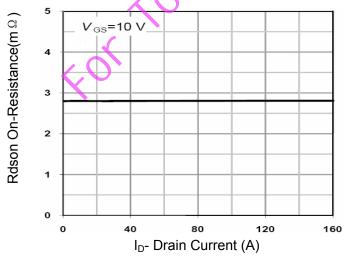


Figure 3 Rdson- Drain Current

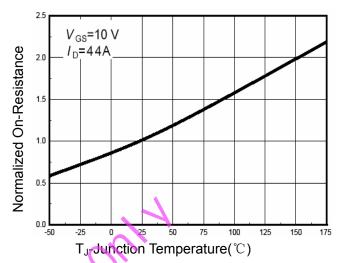


Figure 4 Rdson-Junction Temperature

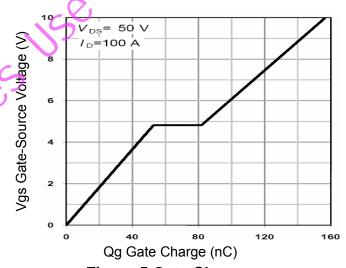


Figure 5 Gate Charge

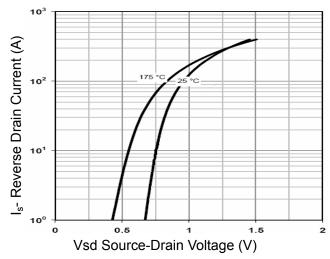
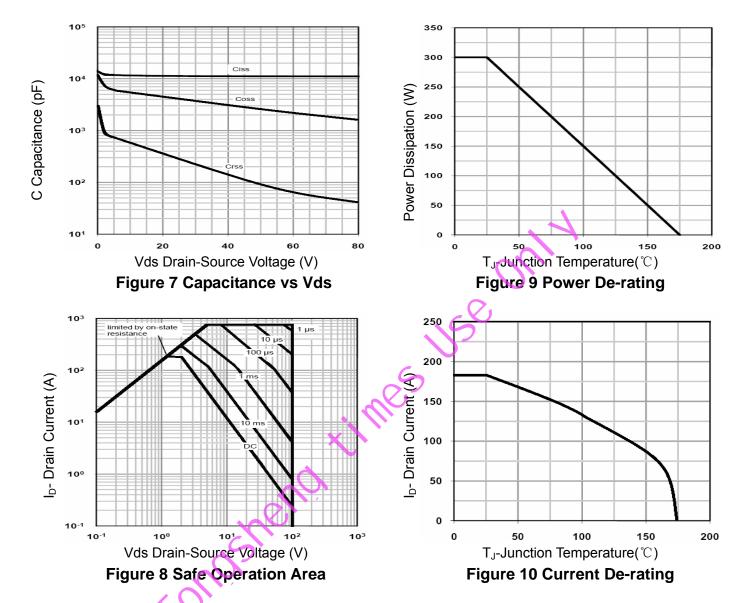


Figure 6 Source- Drain Diode Forward





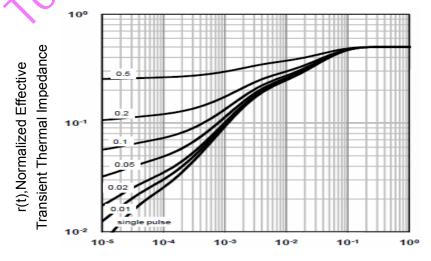


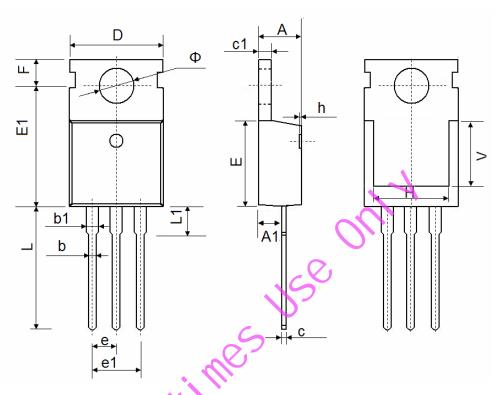
Figure 11 Normalized Maximum Transient Thermal Impedance

Square Wave Pluse Duration(sec)

Pb Free Product



TO-220-3L Package Information



Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1/70	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1 <	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E 🗸	8.9500	9.750	0.352	0.384	
⊞ 1	12.650	12.950	0.498	0.510	
e	2.540 TYP.		0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295 REF.		
Ф	3.400	3.800	0.134	0.150	



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